

TS5A26542

SCDS232E - JUNE 2006-REVISED DECEMBER 2009

0.75-Ω DUAL SPDT ANALOG SWITCH WITH INPUT LOGIC TRANSLATION

Check for Samples: TS5A26542

FEATURES

- Specified Break-Before-Make Switching
- Low ON-State Resistance (0.75 Ω Max)
- Control Inputs Reference to V_{IO}
- Low Charge Injection
- **Excellent ON-State Resistance Matching**
- Low Total Harmonic Distortion (THD)
- 2.25-V to 5.5-V Power Supply (V₊)
- 1.65-V to 1.95-V Logic Supply (V_{10})
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Performance Tested Per JESD 22**
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
 - 300-V Machine Model (A115-A)
- COM Inputs
 - 8000-V Human-Body Model (A114-B, Class II)
 - ±15-kV Contact Discharge (IEC 61000-4-2)

DESCRIPTION

The TS5A26542 is a dual single-pole double-throw (SPDT) analog switch that is designed to operate from 2.25 V to 5.5 V. The device offers a low ON-state resistance with an excellent channel-to-channel ON-state resistance matching, and the break-before-make feature to prevent signal distortion during the transferring of a signal from one path to the another. The device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

The TS5A26542 has a separate logic supply pin (VIO) that operates from 1.65 V to 1.95 V. VIO powers the control circuitry, which allows the TS5A26542 to be controlled by 1.8-V signals.

	T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽²⁾
_	40°C to 85°C	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZT (Pb-free) 0.625-mm max height	Reel of 3000	TS5A26542YZTR	JN_

Table 1. ORDERING INFORMATION

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

YZT: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following (2)character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



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APPLICATIONS

- **Cell Phones**
- **PDAs**
- **Portable Instrumentation**

YZT	PAC	CKA	GE ⁽¹⁾
(BO	ттс	M \	/IEW)
^		~	D

	А	В	С	D	
1	3 2 1	4	9	10	
2	2	5	8	(11)	
3	1	6	7	(12)	

⁽¹⁾The GND balls are internally connected.

	Α	В	С	D
1	IN1	NO1	COM1	NC1
2	VIO	GND	GND	V+
3	IN2	NO2	COM2	NC2



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Configuration	2:1 Multiplexer/Demultiplexer (2 × SPDT)
Number of channels	2
ON-state resistance (r _{on})	0.75 Ω max
ON-state resistance match (Δr_{on})	0.1 Ω max
ON-state resistance flatness (r _{on(flat)})	0.1 Ω max
Turn-on/turn-off time (t _{ON} /t _{OFF})	25 ns/20 ns
Charge injection (Q _C)	15 pC
Bandwidth (BW)	43 MHz
OFF isolation (O _{ISO})	–63 dB at 1 MHz
Crosstalk (X _{TALK})	–63 dB at 1 MHz
Total harmonic distortion (THD)	0.004%
Leakage current (I _{NO(OFF)} /I _{NC(OFF)})	20 nA
Package option	12-pin WCSP

FUNCTION TABLE

COM TO NC

ON

OFF

NC TO COM, NO TO COM,

COM TO NO

ON

SUMMARY OF CHARACTERISTICS⁽¹⁾

(1) $V_+ = 5 V, T_A = 25^{\circ}C$

IN

L

Н

	GRAM	
IN1 (See Note A) COM1	 •	NC1
	•	NC2
COM2 —— IN2 —— (See Note A)	 •	— NO2

A. IN1 and IN2 are control inputs referenced to V_{IO}.



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ABSOLUTE MAXIMUM RATINGS⁽¹⁾ ⁽²⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V+ V _{IO}	Supply voltage range ⁽³⁾		-0.5	6.5	V
V _{NC} V _{NO} V _{COM}	Analog voltage range ⁽³⁾ (4) (5)		-0.5	V ₊ + 0.5	V
I _{I/OK}	Analog port diode current	V_{NO} , V_{NC} , V_{COM} < 0 or V_{NO} , V_{NC} , V_{COM} > V_{+}	-50	50	mA
INC	ON-state switch current		-450	450	
I _{NO} I _{COM}	ON-state peak switch current ⁽⁶⁾	V_{NO} , V_{NC} , $V_{COM} = 0$ to V_+	-700	700	mA
VI	Digital input voltage range ^{(3) (4)}		-0.5	6.5	V
I _{IK}	Digital input clamp current	V ₁ < 0	-50		mA
I ₊ I _{GND}	Continuous current through V ₊ or GND			100	mA
θ_{JA}	Package thermal impedance ⁽⁷⁾			102	°C/W
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(3) All voltages are with respect to ground, unless otherwise specified.

(4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(5) This value is limited to 5.5 V maximum.

(6) Pulse at 1-ms duration <10% duty cycle

(7) The package thermal impedance is calculated in accordance with JESD 51-7.

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EXAS

ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY⁽¹⁾

 $V_{+} = 4.5$ V to 5.5 V, $V_{10} = 1.65$ V to 1.95 V, $T_{A} = -40$ °C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST COND	TIONS	TA	V.	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NO}					0		V+	V
ON-state resistance	r	V_{NO} or $V_{NC} = 2.5 V$,	Switch ON,	25°C	4.5 V		0.5	0.75	Ω
ON-State resistance	r _{on}	$I_{COM} = -100 \text{ mA},$	See Figure 14	Full	4.5 V			0.8	12
ON-state resistance	A	V_{NO} or $V_{NC} = 2.5 V$,	Switch ON,	25°C	45.1		0.05	0.1	0
match between channels	∆r _{on}	$I_{COM} = -100 \text{ mA},$	See Figure 14	Full	4.5 V			0.1	Ω
ON-state resistance		$\begin{array}{l} 0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_{+}, \\ I_{COM} = -100 \text{ mA}, \end{array}$	Switch ON, See Figure 14	25°C			0.1		
flatness	r _{on(flat)}	V_{NO} or $V_{NC} = 1 V$, 1.5 V,	Switch ON,	25°C	4.5 V		0.1	0.25	Ω
		2.5 V, I _{COM} = -100 mA,	See Figure 14	Full				0.25	
		V _{NO} = 1 V, 4.5 V,		25°C		-20	2	20	
NO, NC OFF leakage current	I _{NO(OFF)} , I _{NC (OFF)}		Switch OFF, See Figure 15	Full	5.5 V	-100		100	nA
		V _{NO} = 1 V, 4.5 V,		25°C		-20	2	20	
NC, NO ON leakage current	I _{NO(ON)}	$ \begin{array}{l} V_{NC} \text{ and } V_{COM} = \text{Open}, \\ \text{or} \\ V_{NC} = 1 \text{V}, \ 4.5 \ \text{V}, \\ V_{NO} \text{ and } V_{COM} = \text{Open}, \end{array} $	Switch ON, See Figure 16	Full	5.5 V	-200		200	nA
		$V_{COM} = 1 V,$		25°C		-20	2	20	
COM ON leakage current	I _{COM(ON)}	$\label{eq:VNC} \begin{array}{l} V_{NO} \text{ and } V_{NC} = \text{Open}, \\ \text{or} \\ V_{COM} = 4.5 \text{ V}, \\ V_{NO} \text{ and } V_{NC} = \text{Open}, \end{array}$	See Figure 16	Full	Full 5.5 V	-200		200	nA
Digital Control Input	s (IN1, IN2)	(2)							
Input logic high	V _{IH}	V _{IO} = 1.65 V to 1.95 V		Full		$0.65 \times V_{IO}$		V _{IO}	V
Input logic low	V _{IL}	V _{IO} = 1.65 V to 1.95 V		Full		0		$0.35 \times V_{IO}$	V
Input leakage	Lux Lu	$V_{I} = V_{IO} \text{ or } 0$		25°C	5.5 V	-2		2	nA
current	I _{IH} , I _{IL}			Full	5.5 V	-20		20	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

 (2) All unused digital inputs of the device must be held at V_{IO} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY⁽¹⁾ (continued)

V₊ = 4.5 V to 5.5 V, V_{IO} = 1.65 V to 1.95 V, T_A = -40° C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST C	ONDITIONS	TA	V+	MIN	TYP	MAX	UNIT
Dynamic		1							
Turn-on time	t _{ON}	$V_{COM} = V_+,$	C _L = 35 pF,	25°C	5 V	1	12.5	25	ns
	-014	$R_L = 50 \Omega$,	See Figure 18	Full	4.5 V			30	110
Turn-off time	t _{OFF}	$V_{COM} = V_+,$	$C_{L} = 35 \text{ pF},$	25°C	5 V	1	9.5	20	ns
	-011	$R_L = 50 \Omega$,	See Figure 18	Full	4.5 V			25	
Break-before-make	t _{BBM}	$V_{\rm NC} = V_{\rm NO} = V_{+}/2,$	C _L = 35 pF,	25°C	5 V	1	5	10	ns
time	•BBM	$R_L = 50 \Omega$,	See Figure 19	Full	4.5 V	1		12	no
Charge injection	Q _C	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C _L = 1 nF, See Figure 23	25°C	5 V		15		рС
NO OFF capacitance	C _{NO(OFF)}	$V_{NO} = V_+ \text{ or GND},$ Switch OFF,	See Figure 17	25°C	5 V		37		pF
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 17	25°C	5 V		130		pF
COM ON capacitance	C _{COM(ON)}	$V_{COM} = V_{+} \text{ or GND},$ Switch ON,	See Figure 17	25°C	5 V		130		pF
Digital input capacitance	Cl	$V_{I} = V_{IO} \text{ or GND},$	See Figure 17	25°C	5 V		6.5		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 20	25°C	5 V		43		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega,$ f = 1 MHz,	See Figure 21	25°C	5 V		-63		dB
Crosstalk	X _{TALK}	$ \begin{array}{l} R_L = 50 \ \Omega, \\ f = 1 \ MHz, \end{array} $	See Figure 22	25°C	5 V		-63		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 24	25°C	5 V		0.004		%
Supply									
Positive supply				25°C			5.5	100	1
current	I+	$V_I = V_{IO} \text{ or } GND$		5.5 V				750	nA

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

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Electrical Characteristics for 3.3-V Supply⁽¹⁾

 V_{+} = 3 V to 3.6 V, V_{IO} = 1.65 V to 1.95 V, T_{A} = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDI	TIONS	TA	V.	MIN	TYP	MAX	UNIT
Analog Switch						-			
Analog signal range	V _{COM} , V _{NO}					0		V ₊	V
ON-state resistance	r _{on}	V_{NO} or $V_{NC} = 2 V$,	Switch ON,	25°C	3 V		0.75	0.9	Ω
	·on	$I_{COM} = -100 \text{ mA},$	See Figure 14	Full	•••			1.2	32
ON-state resistance match between channels	Δr _{on}	V_{NO} or V_{NC} = 2 V, 0.8 V, I_{COM} = -100 mA,	Switch ON, See Figure 14	25°C Full	3 V		0.1	0.15 0.15	Ω
ON-state resistance		$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 14	25°C		0.2			
flatness	r _{on(flat)}	$V_{NO} \text{ or } V_{NC} = 0.8 \text{ V}, 2 \text{ V},$	Switch ON,	25°C	3 V		0.1	0.3	Ω
		$I_{COM} = -100 \text{ mA},$	See Figure 14	Full				0.3	
		$V_{NO} = 1 V, 3 V,$		25°C		-20	2	20	nA
NO, NC OFF leakage current	I _{NO(OFF)} , I _{NC} (OFF)		Switch OFF, See Figure 15	Full	3.6 V	-50		50	
		V _{NO} = 1 V, 3 V,		25°C		-10	2	10	
NC, NO ON leakage current	I _{NO(ON)}	$\label{eq:VNC} \begin{array}{l} V_{NC} \text{ and } V_{COM} = \text{Open}, \\ \text{or} \\ V_{NC} = 1 \text{ V}, \text{ 3 V}, \\ V_{NO} \text{ and } V_{COM} = \text{Open}, \end{array}$	Switch ON, See Figure 16	Full	3.6 V	30		30	nA
		$V_{COM} = 1 V,$		25°C		-10	2	10	
COM ON leakage current	I _{COM(ON)}	$\label{eq:VNC} \begin{array}{l} V_{NO} \text{ and } V_{NC} = \text{Open}, \\ \text{or} \\ V_{COM} = 3 \text{ V}, \\ V_{NO} \text{ and } V_{NC} = \text{Open}, \end{array}$	See Figure 16	Full	3.6 V	-30		30	nA
Digital Control Inputs	s (IN1, IN2) ⁽²	2)							
Input logic high	V _{IH}	V _{IO} = 1.65 V to 1.95 V		Full		$0.65 \times V_{IO}$		V _{IO}	V
Input logic low	V _{IL}	V _{IO} = 1.65 V to 1.95 V		Full		0		$0.35 \times V_{IO}$	V
Input leakage current	1 1			25°C	3.6 V	-2		2	
input leakage cullent	I _{IH} , I _{IL}	$V_{I} = V_{IO} \text{ or } 0$		Full	3.0 V	-20		20	nA

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum (2) All unused digital inputs of the device must be held at V_{IO} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY⁽¹⁾ (continued)

 $V_+ = 3 \text{ V}$ to 3.6 V, $V_{IO} = 1.65 \text{ V}$ to 1.95 V, $T_A = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST C	ONDITIONS	TA	V+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	+	$V_{COM} = V_+,$	C _L = 35 pF,	25°C	3.3 V	5	15	30	20
rum-on ume	t _{ON}	$R_L = 50 \Omega$,	See Figure 18	Full	3 V	3		35	ns
Turn-off time	+	$V_{COM} = V_+,$	C _L = 35 pF,	25°C	3.3 V	1	9	20	20
rum-on ume	t _{OFF}	$R_L = 50 \Omega$,	See Figure 18	Full	3 V	1		25	ns
Break-before-make	+	$V_{NC} = V_{NO} = V_{+}/2,$	C _L = 35 pF,	25°C	3.3 V	1	8	13	20
time	t _{BBM}	$R_L = 50 \Omega$,	See Figure 19	Full	3 V	1		15	ns
Charge injection	Q _C	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C _L = 1 nF, See Figure 23	25°C	3.3 V		6.5		рС
NO OFF capacitance	C _{NO(OFF)}	$V_{NO} = V_+ \text{ or GND},$ Switch OFF,	See Figure 17	25°C	3.3 V		38		pF
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 17	25°C	3.3 V		133		pF
COM ON capacitance	C _{COM(ON)}	$V_{COM} = V_{+} \text{ or GND},$ Switch ON,	See Figure 17	25°C	3.3 V		133		pF
Digital input capacitance	Cl	$V_I = V_{IO} \text{ or } GND,$	See Figure 17	25°C	3.3 V		6.5		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 20	25°C	3.3 V		42		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega,$ f = 1 MHz,	See Figure 21	25°C	3.3 V		-63		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega,$ f = 1 MHz,	See Figure 22	25°C	3.3 V		-63		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 24	25°C	3.3 V		0.004		%
Supply									
Positive supply				25°C	2.0.1/		10	50	
current	I+	$V_I = V_{IO} \text{ or } GND$		Full	3.6 V			300	nA

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

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EXAS

ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY⁽¹⁾

 $V_{+} = 2.25$ V to 2.75 V, $V_{IO} = 1.65$ V to 1.95 V, $T_{A} = -40^{\circ}$ C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDI	TIONS	TA	V.	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NO}					0		V ₊	V
ON-state resistance	r	V_{NO} or $V_{NC} = 1.8 V$,	Switch ON,	25°C	2.25 V		1	1.3	Ω
UN-State resistance	r _{on}	$I_{COM} = -100 \text{ mA},$	See Figure 14	Full	2.25 V			1.6	12
ON-state resistance		V_{NO} or $V_{NC} = 1.8 V$,	Switch ON.	25°C	0.05.1/		0.15	0.2	•
match between channels	∆r _{on}	0.8 V, I _{COM} = -100 mA,	See Figure 14	Full	2.25 V			0.2	Ω
ON state registeres		$\begin{array}{l} 0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_{+}, \\ I_{COM} = -100 \text{ mA}, \end{array}$	Switch ON, See Figure 14	25°C			0.5		
ON-state resistance flatness	r _{on(flat)}	$V_{NO} \text{ or } V_{NC} = 0.8 \text{ V}, 1 \text{ V},$	Switch ON,	25°C	2.25 V		0.25	0.5	Ω
		1.8 V, I _{COM} = -100 mA,	See Figure 14	Full				0.6	
		V _{NO} = 0.5 V, 2.2 V,		25°C		-20	2	20	nA
NO, NC OFF leakage current	I _{NO(OFF)} , I _{NC (OFF)}	$\begin{array}{l} V_{COM} = 2.2 \ V, \ 0.5 \ V, \\ V_{NC} = Open, \\ or \\ V_{NC} = 0.5 \ V, \ 2.2 \ V, \\ V_{COM} = 2.2 \ V, \ 0.5 \ V, \\ V_{NO} = Open, \end{array}$	Switch OFF, See Figure 15	Full	2.75 V	-50		50	
		V _{NO} = 0.5 V, 2.2 V,		25°C		-10	2	10	
NC, NO ON leakage current	I _{NO(ON)}	$ \begin{array}{l} V_{NC} \text{ and } V_{COM} = \text{Open},\\ \text{or}\\ V_{NC} = 0.5 \text{ V}, \ 2.2 \text{ V},\\ V_{NO} \text{ and } V_{COM} = \text{Open}, \end{array} $	Switch ON, See Figure 16	Full	2.75 V	-20		20	nA
		V _{COM} = 0.5 V,		25°C		-10	2	10	
COM ON leakage current	I _{COM(ON)}	$ \begin{array}{l} V_{NO} \text{ and } V_{NC} = \text{Open}, \\ \text{or} \\ V_{COM} = 2.2 \text{ V}, \\ V_{NO} \text{ and } V_{NC} = \text{Open}, \end{array} $	Switch ON, See Figure 16	Full	2.75 V	-50		50	nA
Digital Control Inputs	(IN1, IN2) ⁽²)							
Input logic high	V _{IH}	$V_{IO} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		Full		$0.65 \times V_{IO}$		V _{IO}	V
Input logic low	V _{IL}	$V_{IO} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		Full		0		$0.35 \times V_{IO}$	V
Input leakage current	lus lu			25°C	2.75 V	-2		2	nA
input leakage current	I _{IH} , I _{IL}	$V_{I} = V_{IO} \text{ or } 0$		Full	2.15 V	-20		20	ПА

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

 (2) All unused digital inputs of the device must be held at V_{IO} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY⁽¹⁾ (continued)

 $V_{+} = 2.25$ V to 2.75 V, $V_{IO} = 1.65$ V to 1.95 V, $T_{A} = -40^{\circ}$ C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST C	ONDITIONS	TA	V+	MIN	TYP	MAX	UNIT
Dynamic		L			4				
Turn on time		$V_{COM} = V_+,$	C _L = 35 pF,	25°C	2.5 V	5	20	35	~~~
Turn-on time	t _{ON}	$R_L = 50 \Omega$,	See Figure 18	Full	2.25 V	5		40	ns
Turn-off time t	torr	$V_{COM} = V_+,$	C _L = 35 pF,	25°C	2.5 V	2	10	20	ns
Turn-off time t _{OFF}		$R_L = 50 \Omega$,	See Figure 18	Full	2.25 V	2		25	115
Break-before-make	3reak-before-make		C _L = 35 pF,	25°C	2.5 V	1	11	20	ns
time	t _{BBM}	$R_L = 50 \Omega$,	See Figure 19	Full	2.25 V	1		25	113
Charge injection	Q _C	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C _L = 1 nF, See Figure 23	25°C	2.5 V	5			рС
NO OFF capacitance	C _{NO(OFF)}	$V_{NO} = V_{+} \text{ or GND},$ Switch OFF,	See Figure 17	25°C	2.5 V		38		pF
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 17	25°C	2.5 V		135		pF
COM ON capacitance	C _{COM(ON)}	$V_{COM} = V_{+} \text{ or GND},$ Switch ON,	See Figure 17	25°C	2.5 V		135		pF
Digital input capacitance	CI	$V_I = V_{IO} \text{ or GND},$	See Figure 17	25°C	2.5 V		6.5		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 20	25°C	2.5 V		40		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega,$ f = 1 MHz,	See Figure 21	25°C	2.5 V		-63		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega$, f = 1 MHz,	See Figure 22	25°C	2.5 V		-63		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 24	25°C	2.5 V		0.008		%
Supply		-		·	·				
Positive supply	1			25°C	2.75 V		10	25	n۸
current	I+	$V_I = V_{IO} \text{ or } GND$		Full	2.15 V			100	nA

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

TEXAS INSTRUMENTS

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TYPICAL PERFORMANCE

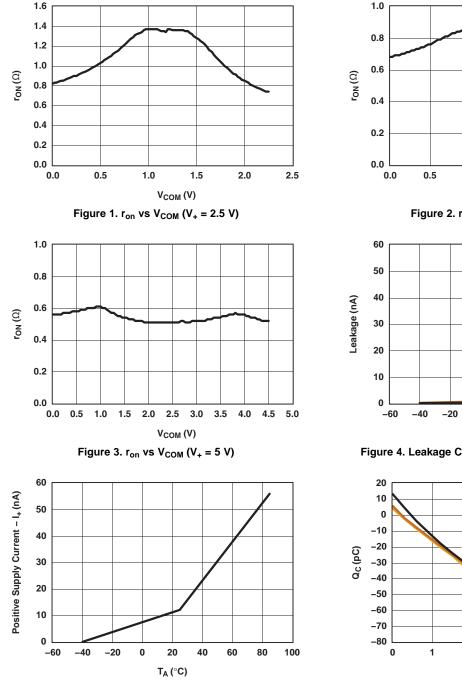


Figure 5. I_+ vs Temperature (V₊ = 5 V)

 $\begin{array}{c}
1.0 \\
0.8 \\
0.6 \\
0.4 \\
0.2 \\
0.0 \\
0.0 \\
0.5 \\
1.0 \\
1.5 \\
2.0 \\
2.5 \\
3.0 \\
V_{COM}(V) \\
Figure 2. r_{on} vs V_{COM}(V_{+} = 3.3 V)
\end{array}$

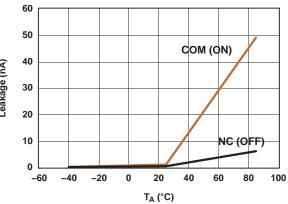


Figure 4. Leakage Current vs Temperature (V₊ = 5 V)

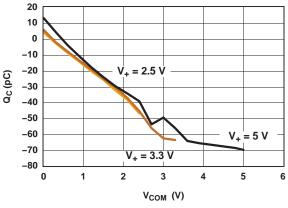
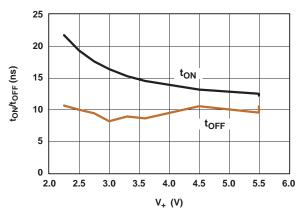


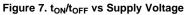
Figure 6. Charge Injection (Q_C) vs V_{COM}



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TYPICAL PERFORMANCE (continued)





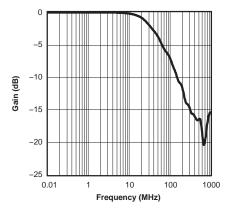
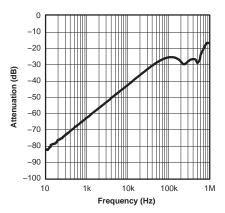


Figure 9. Gain vs Frequency (V₊ = 5 V)





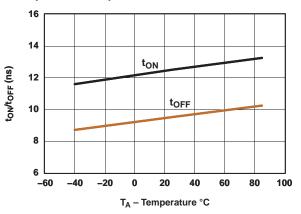


Figure 8. t_{ON}/t_{OFF} vs Temperature (V₊ = 5 V)

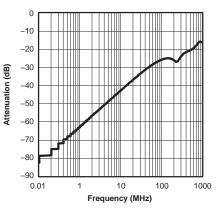


Figure 10. Crosstalk vs Frequency ($V_{+} = 5 V$)

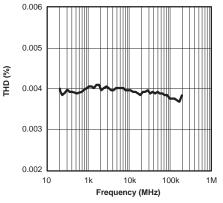
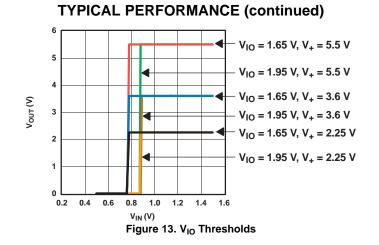


Figure 12. Total Harmonic Distortion vs Frequency (V_+ = 2.5 V)







VI _+ __

IN

GND

÷

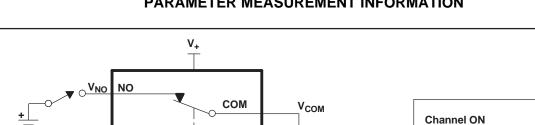
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 $= \frac{\mathsf{V}_{\mathsf{COM}} - \mathsf{V}_{\mathsf{NO}}}{\mathsf{I}_{\mathsf{COM}}} \ \Omega$

ron

 $V_I = V_{IH} \text{ or } V_{IL}$



PARAMETER MEASUREMENT INFORMATION

★ Ісом

-

Figure 14. ON-State Resistance (ron)

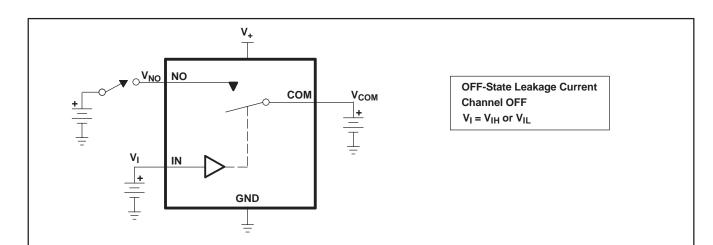
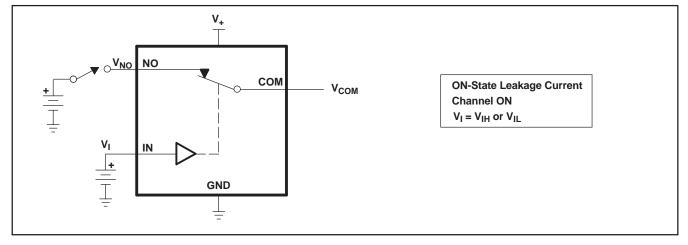


Figure 15. OFF-State Leakage Current (I_{COM(OFF)}, I_{NC(OFF)}, I_{COM(PWROFF)}, I_{NC(PWR(FF)})





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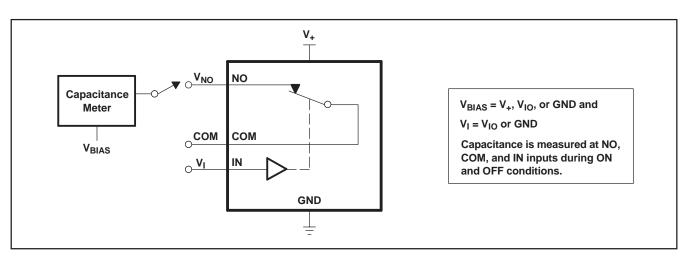
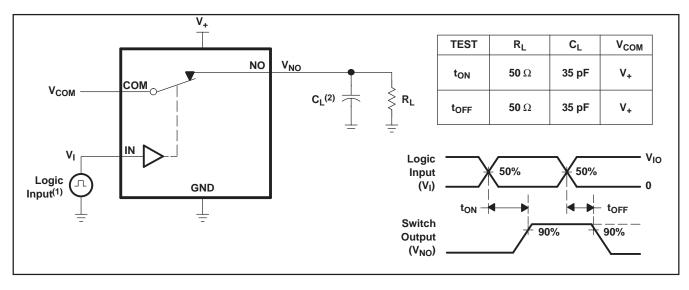


Figure 17. Capacitance (C_I, $C_{COM(OFF)}$, $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NC(ON)}$)



NOTES: A. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r < 5 ns, t_f < 5 ns. B. C_L includes probe and jig capacitance.

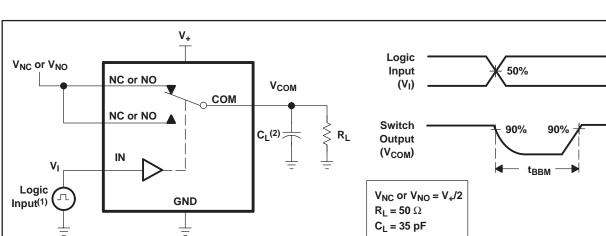
Figure 18. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})



 v_{IO}

0

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PARAMETER MEASUREMENT INFORMATION (continued)

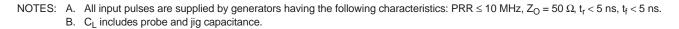


Figure 19. Break-Before-Make Time (t_{BBM})

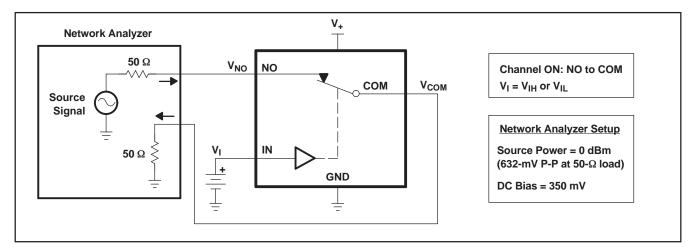


Figure 20. Bandwidth (BW)





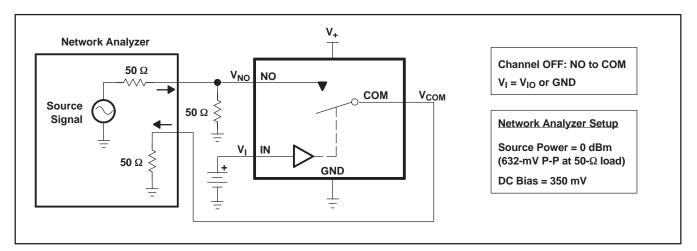


Figure 21. OFF Isolation (O_{ISO})

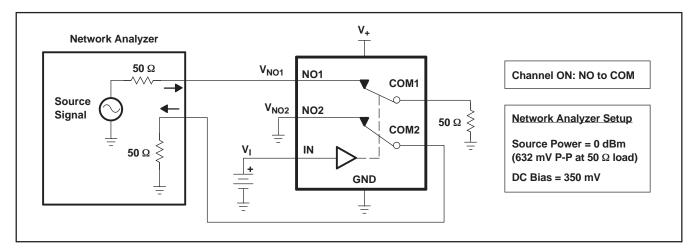
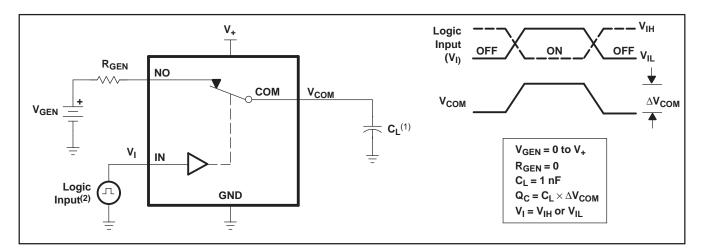


Figure 22. Crosstalk (X_{TALK})



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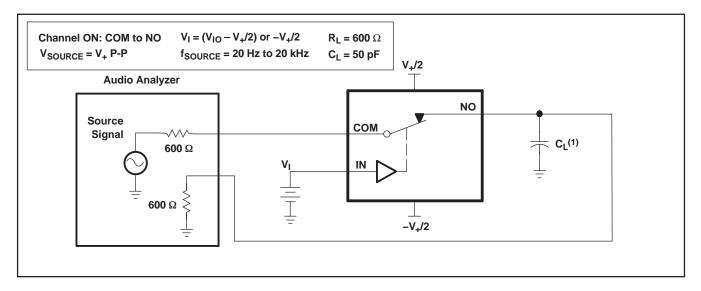
PARAMETER MEASUREMENT INFORMATION (continued)



NOTES: A. C_L includes probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f < 5 ns, t_f < 5 ns.

Figure 23. Charge Injection (Q_c)



NOTES: A. C_L includes probe and jig capacitance.

Figure 24. Total Harmonic Distortion (THD)



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TS5A26542YZTR	ACTIVE	DSBGA	YZT	12	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(JN2, JN7, JNN)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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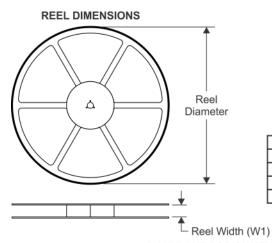
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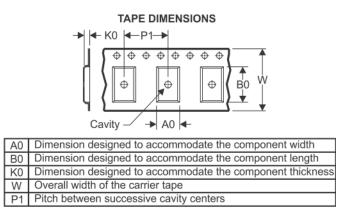
PACKAGE MATERIALS INFORMATION

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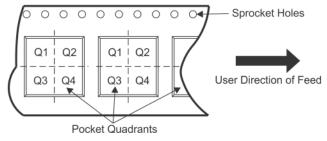
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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package	Package	Pins
*All dimensions are nominal			

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A26542YZTR	DSBGA	YZT	12	3000	178.0	9.2	1.49	1.99	0.75	4.0	8.0	Q2

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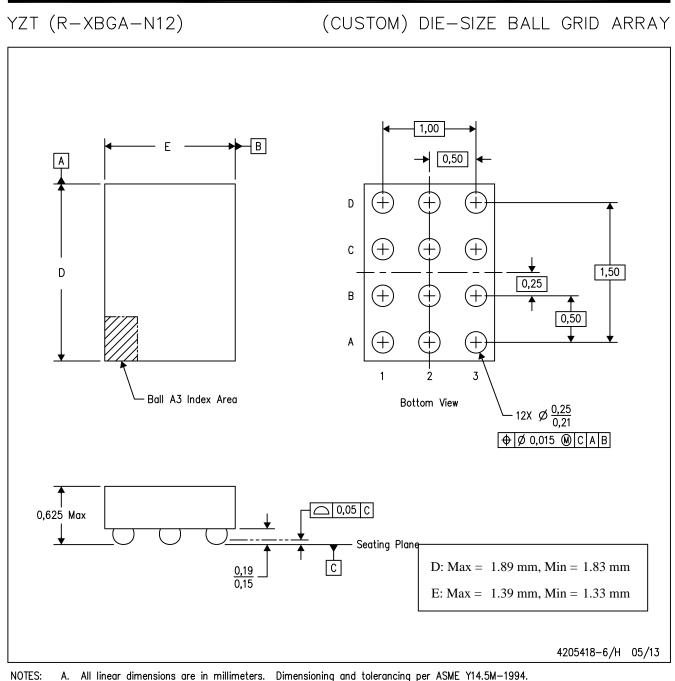
PACKAGE MATERIALS INFORMATION

18-Jan-2020



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A26542YZTR	DSBGA	YZT	12	3000	220.0	220.0	35.0



B. This drawing is subject to change without notice.

C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.



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